



MBRF1535CT THRU MBRF15100CT

Isolation 15.0 AMPS. Schottky Barrier Rectifiers



Voltage Range
35 to 100 Volts
Current
15.0 Amperes

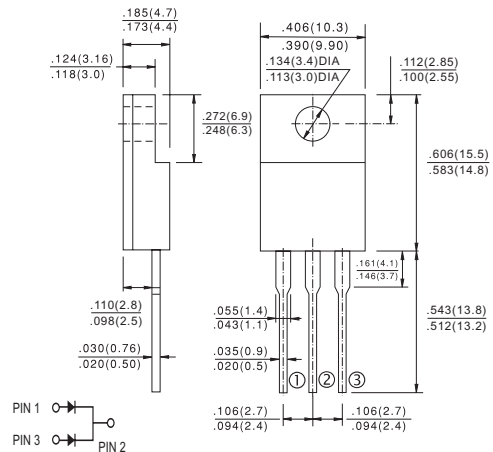
Features

- ✦ Plastic material used carries Underwriters Laboratory Classifications 94V-0
- ✦ Metal silicon junction, majority carrier conduction
- ✦ Low power loss, high efficiency
- ✦ High current capability, low forward voltage drop
- ✦ High surge capability
- ✦ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ✦ Guardring for transient protection
- ✦ High temperature soldering guaranteed: 260°C/10 seconds, 0.25"(6.35mm) from case

Mechanical Data

- ✦ Cases: ITO-220AB molded plastic body
- ✦ Terminals: Leads solderable per MIL-STD-750, Method 2026
- ✦ Polarity: As marked
- ✦ Mounting position: Any
- ✦ Mounting torque: 5 in. - lbs. max
- ✦ Weight: 0.08 ounce, 2.24 grams

ITO-220AB



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	MBRF 1535CT	MBRF 1545CT	MBRF 1550CT	MBRF 1560CT	MBRF 1590CT	MBRF 15100CT	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	35	45	50	60	90	100	V
Maximum RMS Voltage	V_{RMS}	24	31	35	42	63	70	V
Maximum DC Blocking Voltage	V_{DC}	35	45	50	60	90	100	V
Maximum Average Forward Rectified Current at $T_c=105^\circ\text{C}$	$I_{(AV)}$	15						A
Peak Repetitive Forward Current (Rated V_R , Square Wave, 20KHz) at $T_c=105^\circ\text{C}$	I_{FRM}	15.0						A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	150						A
Peak Repetitive Reverse Current (Note 1)	I_{RRM}	1.0			0.5			A
Maximum Instantaneous Forward Voltage at (Note 2) $I_F=7.5\text{A}, T_c=25^\circ\text{C}$ $I_F=7.5\text{A}, T_c=125^\circ\text{C}$ $I_F=15\text{A}, T_c=25^\circ\text{C}$ $I_F=15\text{A}, T_c=125^\circ\text{C}$	V_F	-	-	0.75	0.65	0.92	0.82	V
Maximum Instantaneous Reverse Current @ $T_c=25^\circ\text{C}$ at Rated DC Blocking Voltage (Note 2) @ $T_c=125^\circ\text{C}$	I_R	0.1	15.0	1.0	50.0	0.1	-	mA mA
Voltage Rate of Change (Rated V_R)	dV/dt	10,000						V/ μs
Maximum Thermal Resistance Per Leg (Note 3)	$R\theta_{JC}$	3.5						$^\circ\text{C}/\text{W}$
Operating Junction Temperature Range	T_J	-65 to +150						$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-65 to +175						$^\circ\text{C}$

Notes: 1. 2.0us Pulse Width, $f=1.0\text{ KHz}$

2. Pulse Test: 300us Pulse Width, 1% Duty Cycle

3. Thermal Resistance from Junction to Case with heatsink size of 2" x 3" x 0.25" AL-place

RATINGS AND CHARACTERISTIC CURVES (MBRF1535CT THRU MBRF15100CT)

FIG. 1- FORWARD CURRENT DERATING CURVE

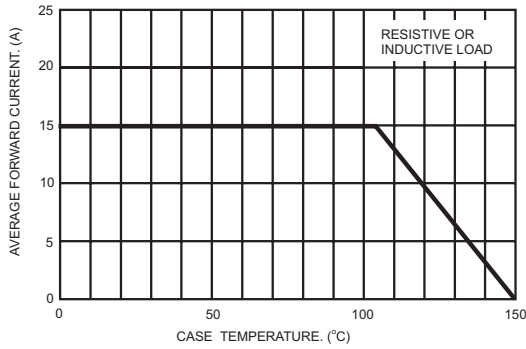


FIG. 2- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT PER LEG

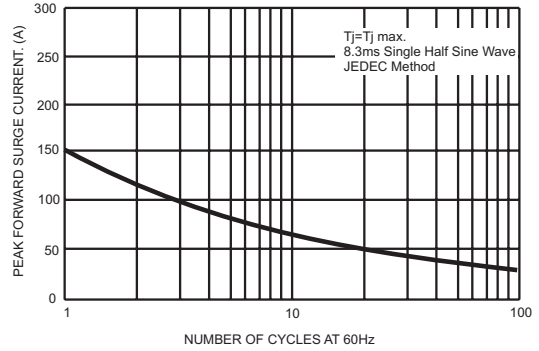


FIG. 3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS PER LEG

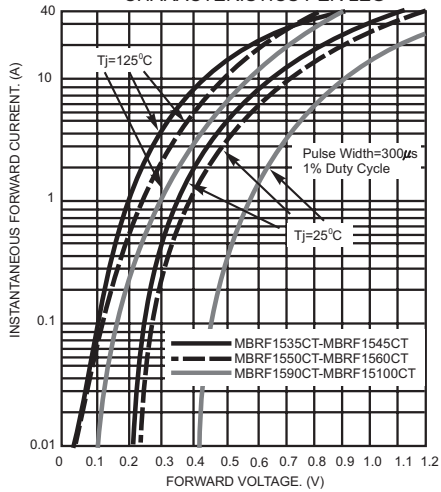


FIG. 4- TYPICAL REVERSE CHARACTERISTICS PER LEG

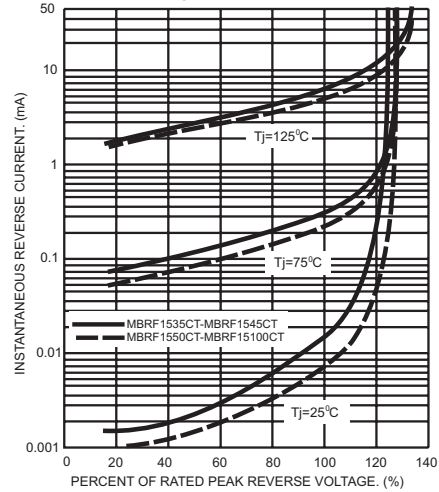


FIG. 5- TYPICAL JUNCTION CAPACITANCE PER LEG

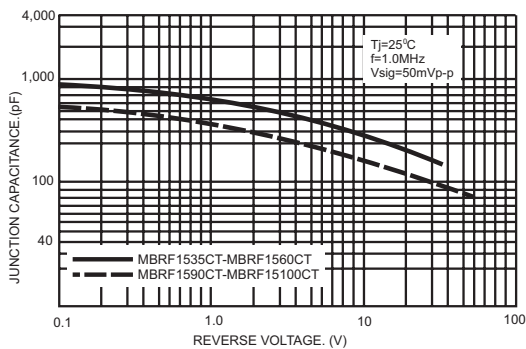


FIG. 6- TYPICAL TRANSIENT THERMAL CHARACTERISTICS PER LEG

